



An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company

## PNP COMPLEMENTARY SILICON HIGH VOLTAGE TRANSISTOR



CC5401 (9AW) TO-92 BCE

MARKING: CC

5401

# High Voltage PNP Transistor For General Purpose And Telephony Applications.

### **ABSOLUTE MAXIMUM RATINGS.**

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector -Emitter Voltage	VCEO	150	V
Collector -Base Voltage	VCBO	160	V
Emitter -Base Voltage	VEBO	5.0	V
<b>Collector Current Continuous</b>	IC	600	mA
Power Dissipation @Ta=25 degC	PD	625	mW
Derate Above 25 deg C		5.0	mw/deg C
Power Dissipation @Tc=25 degC	PD	1.5	W
Derate Above 25 deg C		12	mw/deg C
Junction Temperature	Tj	150	deg C
Storage Temperature	Tstg	-55 to +150	deg C
THERMAL RESISTANCE			
Junction to Case	Rth(j-c)	83.3	deg C/W
Junction to Ambient	Rth(j-a)	200	deg C/W

ELECTRICAL CHARACTERISTICS	(Ta=25 deg	g C Unless	Otherwise S	Specified)
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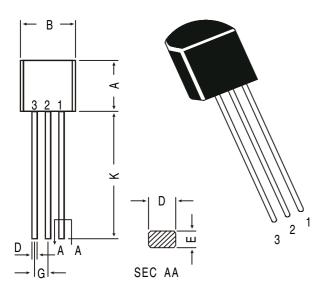
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector -Emitter Voltage	VCEO*	IC=1uA,IB=0	150	-	-	V
Collector -Base Voltage	VCBO	IC=100uA.IE=0	160	-	-	V
Emitter -Base Voltage	VEBO	IE=10uA, IC=-0	5.0	-	-	V
Collector-Cut off Current	ICBO	VCB=160V, IE=0	-	-	50	nA
		Ta=100 deg C				
		VCB=160V, IE=0	-	-	50	uA
	ICEO	VCE=150V, IB=0			1.0	uA
Emitter-Cut off Current	IEBO	VEB=4V, IC=0	-	-	50	nA
DC Current Gain	hFE*	IC=1mA,VCE=5V	50	-	-	
		IC=10mA,VCE=5V	80	-	320	
		IC=50mA,VCE=5V	50	-	-	

FI FCTRICAL	CHARACTERISTICS (T	2-25 dag C Unioss	Otherwise Specified)

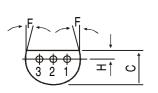
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U	C5	41	"

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Emitter Saturation Voltage	VCE(Sat)*	IC=10mA,IB=1mA	-	-	0.2	V
		IC=50mA,IB=5mA	-	-	0.5	V
Base Emitter Saturation Voltage	VBE(Sat) *	IC=10mA,IB=1mA	-	-	1.0	V
		IC=50mA,IB=5mA	-	-	1.0	V
<b>Dynamic Characteristics</b>						
Small Signal Current Gain	hfe	IC=1mA, VCE=10V	80	-	320	
		f=1KHz				
Transition Frequency	ft	VCE=10V,IC=10mA,	100	-	300	MHz
		f=100MHz				
Output Capacitance	Cobo	VCB=10V, IE=0	-	-	6.0	pF
		f=1MHz				
Noise Figure	NF	VCE=5V, IC=250uA	-	-	8.0	dB
		Rs=1kohms, f=10Hz				
		to 15.7kHz				

# **TO-92 Plastic Package**



All diminsions in mm.



PIN	N CONFIGURATION
1	BASE

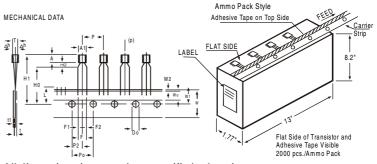
2. COLLECTOR

**Packing Detail** 

3. EMITTER

DIM	MIN.	MAX.
Α	4.32	5.33
В	4.45	5.20
C	3.18	4.19
D	0.41	0.55
Е	0.35	0.50
F	5 D	EG
G	1.14	1.40
Н	1.14	1.53
K	12.70	_

### **TO-92 Transistors on Tape and Ammo Pack**



#### All dimensions in mm unless specified otherwise

ITEM			SPECIFICATION			25111210
I I E M	SYMBOL	MIN.	NOM.	MAX.	TOL.	REMARKS
BODY WIDTH	A1	4.0		4.8		
BODY HEIGHT BODY THICKNESS	A T	4.8 3.9		5.2 4.2		
PITCH OF COMPONENT	P	0.5	12.7	'	±1	
FEED HOLE PITCH	Po		12.7		±0.3	CUMULATIVE PITCH ERROR 1.0 mm/20
FEED HOLE CENTRE TO COMPONENT CENTRE	P2		6.35		±0.4	PITCH TO BE MEASURED AT BOTTOM OF CLINCH
DISTANCE BETWEEN OUTER LEADS	F		5.08		+0.6 -0.2	BOTTOW OF CLINCIT
COMPONENT ALIGNMENT TAPE WIDTH	△h W		0 18	1	±0.5	AT TOP OF BODY
HOLD-DOWN TAPE WIDTH	Wo		6		±0.5 ±0.2	
HOLE POSITION	W1		9		+0.7 -0.5	
HOLD-DOWN TAPE POSITION	W2		0.5		±0.2	
LEAD WIRE CLINCH HEIGHT COMPONENT HEIGHT	Ho H1		16	23.25	±0.5	
LENGTH OF SNIPPED LEADS	Ľ			11.0		
FEED HOLE DIAMETER	Do		4	١,,	±0.2	40000
TOTAL TAPE THICKNESS LEAD - TO - LEAD DISTANCEF1,	t F2		2.54	1.2	+0.4 -0.1	t1 0.3 - 0.6
CLINCH HEIGHT PULL - OUT FORCE	H2 (P)	6N		3	0.1	

- NOTES

  1. MAXIMUM ALIGNMENT DEVIATION BETWEEN LEADS NOT TO BE GREATER THAN 0.2 mm.

  2. MAXIMUM NON-CUMULATIVE VARIATION BETWEEN TAPE FEED HOLES SHALL NOT EXCEED 1 mm IN 20 PITCHES.

  3. HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO
- EXPOSURE OF ADHESIVE.

  4. NO MORE THAN 3 CONSECUTIVE MISSING COMPONENTS ARE PERMITTED.

  5. A TAPE TRAILER, HAVING AT LEAST THREE FEED HOLES ARE REQUIRED AFTER THE LAST COMPONENT.

  6. SPLICES SHALL NOT INTERFERE WITH THE SPROCKET FEED HOLES.

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX			
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt	
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5.0K	17" x 15" x 13.5"	80.0K	23 kgs	
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2.0K	17" x 15" x 13.5"	32.0K	12.5 kgs	

#### **Notes**

#### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.
Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290
e-mail sales@cdil.com www.cdil.com